

# Foundations of Physics 2B

# Condensed Matter Physics

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# Lecture 1

# 1.1 Describing Crystals

- regular periodic array of atoms highly defined
- ➤ x-rays discovered in 1912
  - ⇒ diffraction of x-rays key to studying crystals
- > crystals classified by certain physical properties
- ➤ a perfect crystal is assumed to be a regular array of repeating points
  - we can construct a set of theoretical points in 3D (defined by vectors), called a lattice
- ▶ lattice described by unit vectors  $\underline{a}_1, \underline{a}_2, \underline{a}_3$ , called the lattice constants
- ➤ lattice given physical reality by placing atoms at lattice points
  - → these atoms are called a basis there can be more than one atom in a basis, e.g. NaCl
- $\blacktriangleright$  use the relationship, where:  $\underline{r},\underline{r}'$  are points on the lattice;  $a_i$  are unit vectors; and  $n_i$  are scalar multiples -

$$\underline{r}' = \underline{r} + n_1 \underline{a}_1 + n_2 \underline{a}_2 + n_3 \underline{a}_3$$

- ➤ it is called a primitive lattice if this equation cannot be reduced
- ➤ think of lattices as 3D constructs for filling space
- > crystals have a high degree of symmetry

# 1.2 Symmetry Operators

- 1. translation
- 2. rotation
- 3. reflection
- 4. inversion
- 5. combinations of above
- ➤ a lattice should remain invariant under specific symmetry operations
- ➤ point operators in 2D lead to 2D lattices, of which you can get different types -
  - 1. square
  - 2. hexagonal
  - 3. rectangular
  - 4. centred rectangular
  - 5. oblique parallelogram
  - ⇒ cannot get a five-fold symmetry shape

#### 1.3 Three-Dimensional Lattices

- ➤ there are seven basic crystal systems
  - 1. triclinic
  - 2. monoclinic
  - 3. orthorhombic
  - 4. tetragonal
  - 5. rhombohedral (trigonal)
  - 6. hexagonal
  - 7. cubic
- ➤ use parameters to define these -
  - **⇒** p primitive
  - **→** i interstitial
  - **⇒** f face-centred
  - $\Rightarrow$  c base-centred
- ➤ by varying the parameters for each basic type (see table in lecture summary), get 14 Bravais lattices in 3D
  - ⇒ these are the basic building blocks of all crystals

#### 1.4 Miller Indices

- ➤ key concept for categorising crystals
- ➤ describe a particular crystallographic plane or orthogonal direction in crystal
- ➤ effectively describes crystals as families of parallel planes
- ➤ method for determining the index:
  - 1. find the intercepts of plane on crystal axes the three lattice constants
  - 2. take the reciprocal of these constants
  - 3. reduce to 3 integers with the same ratio
  - 4. this gives the index of the plane, using the notation (hkl), or  $(\nu_1\nu_2\nu_3)$  in Kittel
  - 5. if one of the indices is negative, put a bar above the magnitude
- > separation between planes:

$$d = \frac{1}{\sqrt{\frac{h^2}{a_1^2} + \frac{k^2}{a_2^2} + \frac{l^2}{a_3^2}}}$$

➤ For a cubic, this reduces to

$$d_{hkl} = \frac{a}{\sqrt{N}}$$

#### Lecture 2

# 2.1 X-Ray Diffraction

- $\triangleright$  crystal is defined by a set of parallel planes separated by distance d
- ➤ waves incident on crystals will be diffracted developed by Bragg and lead to the law of x-ray diffraction
- ➤ for each wave will experience specular reflection small reduction in intensity
- $\blacktriangleright$  path length difference  $A \to B \to C = 2d \sin \theta$
- ➤ if path length is equal to an integer multiple of the wavelength of wave, get constructive interference
- ➤ Bragg Law:

$$2d\sin\theta = n\lambda$$

- $\blacktriangleright$  typically,  $\lambda \approx 0.15 \, nm$  for x-rays
- $\blacktriangleright$  it is observed that each plane of atoms reflects  $10^{-3} 10^{-5}$  of the intensity
- ➤ Bragg law is a consequence of periodic structure of crystals
- ➤ Fourier analysis is used

#### 2.2Electron Density

rystal lattice is defined by translation vector,

$$\underline{T} = n_1 \underline{a}_1 + n_2 \underline{a}_2 + n_3 \underline{a}_3$$

- $\triangleright$  crystal is invariant under T translation
- $\blacktriangleright$  many physical properties related to electron density,  $n(\underline{r})$
- rystal symmetry  $\implies n(\underline{r}) = n(\underline{r} + \underline{T})$ , local electron environment is also invariant under  $\underline{T}$
- > consider electron density in one dimension:

$$n(x) = n_0 + \sum_{p} \left[ c_p \cos\left(\frac{2\pi xp}{a}\right) + s_p \sin\left(\frac{2\pi xp}{a}\right) \right]$$

- $\triangleright p \in \mathbb{N}$ ; a = the lattice constant; and x = distance
- ightharpoonup crystal symmetry also  $\implies n(x) = n(x+a)$

#### Reciprocal Lattice Points 2.3

- ➤ arguments of sin and cos are called reciprocal lattice points
  - there is a factor of  $\frac{2\pi}{a}$  requires functions to have correct periodicity units cos, sin are dimensionless;  $\frac{2\pi p}{a}$  is the basis of summation only certain values are allowed by the relationship above

$$n(x) = \sum_{p} n_{p} e^{\frac{i2\pi px}{a}}$$

- ➤ allowed points in sin() and cos() are equivalent to families of planes described by Miller indices (hkl)
- ➤ in 3D:

$$n(\underline{r}) = \sum_{G} n_G e^{\underline{G} \cdot \underline{r}}, \ G = \text{reciprocal lattice vectors}$$

- $\triangleright$  G is defined as the family of reciprocal lattice points in 3D each describing a family of crystal planes
- $\triangleright$   $b_1, b_2, b_3$  are the reciprocal lattice unit vectors, units of frequency

$$b_1 = 2\pi \frac{\underline{a}_2 \times \underline{a}_3}{\underline{a}_1 \cdot (\underline{a}_2 \times \underline{a}_3)} \; ; \; b_2 = 2\pi \frac{\underline{a}_3 \times \underline{a}_1}{\underline{a}_1 \cdot (\underline{a}_2 \times \underline{a}_3)} \; ; \; b_3 = 2\pi \frac{\underline{a}_1 \times \underline{a}_2}{\underline{a}_1 \cdot (\underline{a}_2 \times \underline{a}_3)}$$

- $\triangleright$   $a_i$  are unit vectors of crystal
- $ightharpoonup a_i \cdot b_j = 2\pi \delta_{ij}$  delta function

$$\underline{G} = \nu_1 \underline{b}_1 + \nu_2 \underline{b}_2 + \nu_3 \underline{b}_3$$

$$n(\underline{r} + \underline{T}) = \sum_{G} n_G e^{i\underline{G} \cdot \underline{r}} \underbrace{e^{i\underline{G} \cdot \underline{T}}}_{2\pi \times p}$$

### Lecture 3

# 3.1 X-Ray Diffraction

- $\blacktriangleright$  incident electromagnetic wave on crystal  $\exp[9(k \cdot r)]$ 
  - $\Rightarrow$  k is the wavevector of the x-ray
- ➤ elastic process conservation of energy
- ➤ assume interaction between electric field of wave and electrons in atom
- $\triangleright$  electron density n(r)

➤ scattered wave is described by

$$F = \int n(\underline{r}) \exp \left[ i((\underline{k} - \underline{k}') \cdot \underline{r}) \right] dV$$
$$= \int n(\underline{r}) \exp \left[ i(\underline{\Delta k} \cdot \underline{r}) \right] dV$$

- ightharpoonup  $\underline{\Delta}\underline{k} = \underline{k} \underline{k}'$
- $\blacktriangleright$  elastic scattering  $|\underline{k}| = |\underline{k}'|$
- $\blacktriangleright$   $\Delta k$  scattering vector
  - ightharpoonup for Bragg condition  $\Delta k = G$

$$F = \sum_{G} \int n_{G} \exp\left[i(\underline{G} - \underline{\Delta}\underline{k}) \cdot \underline{r}\right]$$

➤ alternative formulation of Bragg condition -

- $\blacktriangleright$  n.b.  $\underline{\Delta k}$  has equivalent positive and negative values
- 3.2 Brillouin Zones
  - ➤ analogy to unit cells in reciprocal space
  - ➤ first Brillouin zone is Wigner-Seitz primitive cell in reciprocal lattice
    - ⇒ used to describe a wide range of physical properties
  - ➤ construct Brillouin zone:
    - 1. select origin in reciprocal space
    - 2. draw reciprocal lattice vector to all nearest neighbours
    - 3. perpendicular bisectors enclose first Brillouin zone

### **Examples of Reciprocal Lattices**

➤ simple cubic lattice:

$$\begin{array}{ll} \underline{a}_1 = a\hat{x} & \underline{a}_2 = a\hat{y}, & \underline{a}_3 = a\hat{z} \\ \underline{b}_1 = \frac{2\pi}{a}\hat{x} & \underline{b}_2 = \frac{2\pi}{a}\hat{y} & \underline{b}_3 = \hat{z} \end{array}$$

- reciprocal lattice is a simple cube with lattice constant  $\frac{2\pi}{a}$
- ➤ body centred cubic lattice:

$$\underline{a}_1 = \frac{1}{2}a(-\hat{x} + \hat{y} + \hat{z})$$

$$\underline{a}_2 = \frac{1}{2}a(\hat{x} - \hat{y} + \hat{z})$$

$$\underline{a}_3 = \frac{1}{2}a(\hat{x} + \hat{y} - \hat{z})$$

$$\underline{b}_1 = \frac{2\pi}{a}(\hat{y} + \hat{z})$$

$$\underline{b}_2 = \frac{2\pi}{a}(\hat{x} + \hat{z})$$

$$\underline{b}_3 = \frac{2\pi}{a}(\hat{x} + \hat{y})$$

- ➤ these are primitive lattice vectors of fcc (face centre cubic) lattice
- ➤ similarly, reciprocal of fcc lattice is bcc lattice
- **3.3** Structure Factor
  - ➤ structure factor describes intensity of Bragg peaks
    - ⇒ arises because Bragg law considers parallel planes but can also get interference within unit cell

➤ integral over unit cell describes total scattered intensity

$$F_G = N \int_{cell} n(\underline{r}) \exp\left[-i\underline{G} \cdot \underline{r}\right] = NS_G$$

- $\triangleright$  N is the total number of cells;  $S_G$  is the structure factor for a single cell
- $\blacktriangleright$  define origin at  $\underline{r} = 0$
- $\blacktriangleright$  consider  $n(\underline{r})$  as sum over all unique atoms in unit cell

$$n(\underline{r}) = \sum_{j=1}^{S} n_j (\underline{r} - \underline{r}_j)$$

$$S_G = \sum_{j} \exp\left[-i\underline{G} \cdot \underline{r}\right] \int n_j (\underline{\rho}) \exp\left[-i\underline{G} \cdot \underline{\rho}\right]$$

$$= \sum_{j} f_j \exp\left[-i\underline{G} \cdot \underline{r}_j\right]$$

$$S_G(\nu_1 \nu_2 \nu_3) = \sum_{j} f_j \exp\left[-i2\pi(\nu_1 x_j + \nu_2 y_j + \nu_3 z_j)\right]$$

- $ightharpoonup 
  ho = \underline{r} r_j, \underline{r}_j$  is position of unique atom in unit cell;  $f_j$  is atom form factor scattering of one atom
- $ightharpoonup 
  u_1 
  u_2 
  u_3 = hkl$  describing Bragg peak;  $(x_j, y_j, z_j)$  is position coordinates within unit cell
- rightharpoonup for bcc lattice have two unique atoms at coordinates  $(000), (\frac{1}{2}, \frac{1}{2}, \frac{1}{2})$
- $\blacktriangleright$  evaluate  $S_G \implies S = 0$  when  $\nu_1 + \nu_2 + \nu_3 = \text{odd integer}$ ; S = 2f when  $\nu_1 + \nu_2 + \nu_3 = \text{even integer}$
- ► fcc lattice 4 atoms  $(0,0,0), (0,\frac{1}{2},\frac{1}{2}), (\frac{1}{2},0,\frac{1}{2}), (\frac{1}{2},\frac{1}{2},0)$ 
  - $\Rightarrow$  S = 0 when integers mixed
  - $\Rightarrow$  S = 4f when integers all odd or all even

# Lecture 4

### 4.1 Crystal Bonding

- ➤ bonding is a stable equilibrium between attractive and repulsive force
- repulsive arises from electrons being fermions
  - → no two fermions occupy the same quantum state
  - ⇒ as electrons from adjacent atoms overlap, increases energy to satisfy Pauli exclusion principle
- ➤ different types of bonds have different attractive forces:
- 1. Van Der Waals bonding exists in almost all solid system very weak force, usually only observed at low temperatures in noble gases
  - ➤ attraction is between electric dipoles
    - (a) permanent
    - (b) permanent-induced
    - (c) two induced dipoles
  - ➤ spherically symmetrical atom when brought closer to another atom, electron distribution adjusts because of Coulomb potential
  - ➤ can consider movement of charge as electric dipole:
    - $\Rightarrow$  amount of charge, q, moving distance,  $L, \rightarrow$  dipole moment = p = qL
    - ightharpoonup electric dipole consists of charge +q and -q separated by L
    - ⇒ at arbitrary point, electric potential

$$V = \frac{Q}{4\pi\epsilon_0} \left( \frac{1}{r_b} - \frac{1}{r_a} \right)$$

**⇒** it can be shown that

$$V(r) = \frac{\underline{p} \cdot \hat{r_1}}{4\pi\epsilon_0 r^2}$$

- $\blacktriangleright$  where p is the electric dipole vector, and  $\hat{r}_1$  is the unit vector along <u>r</u>
- ⇒ show potential energy and force are

$$U(r) = \frac{A}{r^6}$$
$$F(r) = -\frac{dU}{dr} = \frac{A}{r^7}$$

- ➤ modelling Pauli repulsion very complex
  - **⇒** approximate using empirical function
  - $\Rightarrow$  experimental data on solid gases shows that the function is of the form  $\frac{B}{r^{12}}$  fits data

$$U(r) = 4\epsilon \left[ -\left(\frac{\sigma}{r}\right)^6 + \left(\frac{\sigma}{r}\right)^{12} \right]$$

- $\Rightarrow$  this is the Lennard Jones 6 12 potential models interatomic potential in Van Der Waals solids
- 2. other examples of bonding
  - (a) ionic bonding crystals made of positive and negative energy
    - ➤ many salts are under this (NaCl, LiF, MgCl)
    - > overall energy of ionic crystal ionisation energy, electron affinity
    - ➤ energy electrostatic attraction

$$U(r) = -\frac{e^2}{4\pi\epsilon_0 r}$$

- ➤ this considers only nearest neighbours
- ➤ in ionic crystals, energy must also consider other ions not just nearest neighbours
- interaction of all ions described by modelling constant
  - → face centred cube crystal has modelling constant of 1.7475
- (b) covalent crystals sharing of electrons, generally occurs in systems of similar atoms (e.g. silicon semiconductor, diatomic gases)
  - > covalent bonding can only be described using QM
  - $\blacktriangleright$  two electrons, spin =  $\frac{1}{2}$ 
    - $\rightarrow \uparrow \downarrow \rightarrow S = 0$  spin antisymmetric
    - $\Rightarrow \uparrow \uparrow \rightarrow S = 1$  spin symmetric
    - ▶ when spin is antisymmetric, position (wavefunction) is symmetric or vice versa
    - ⇒ large electron density between atoms forms a bond

#### Lecture 5

- ➤ consider crystals as system of vibrating atoms
- ➤ family of excitations in solids, elastic waves phonons
- range of phenomena suggests atoms vibrate
- $\blacktriangleright$  describe crystal as series of parallel planes denoted by  $s, s \pm 1, s \pm 2, \cdots$
- $\blacktriangleright$  describe position of plane using coordinate  $u_s, u_{s\pm 1}, \dots, u_s$  is the displacement from the equilibrium
- ➤ longitudinal and transverse waves exist
- > physics to describe motion?
  - $\rightarrow$  Hooke's law elastic wave, restoring force, linear function of  $u_S$
- ➤ energy of oscillating system:

$$E = \frac{1}{2}kA^2$$

- $\blacktriangleright$  spring constant  $\omega = \sqrt{\frac{k}{m}}$
- ➤ elastic energy is a quadratic function of displacement from mean position

- ➤ need to know the force exerted on individual planes
- ➤ assume only nearest neighbour interactions apply
- ➤ forces acting on plane s:

$$F_s = c(u_{s+1} - u_s) + c(u_{s-1} - u_s)$$

➤ c is a force constant for the nearest neighbour

$$M\frac{d^2u_s}{dt^2} = c(u_{s+1} + u_{s-1} - 2u_s)$$

➤ Assume SHM:

$$\frac{d^2u_s}{dt^2} = -\omega^2 u_s$$

➤ Equation relates motion of planes:

$$-M\omega^2 u_s = c(u_{s+1} + u_{s-1} - 2u_s)$$

➤ by substitution, the general form of equation is:

$$u_{s\pm 1} = U \exp\left[i(s\pm 1)ka\right] = U \exp\left(iska\right) \exp\left(\pm ika\right)$$

ightharpoonup U is the maximum amplitude, k is the wavevector of the elastic wave, and a is the spacing of adjacent planes

$$-\omega^2 M u \exp(iska) = CU \left\{ \exp[i(s+1)ka] + \exp[i(s-1)ka] - 2\exp[iska] \right\}$$

$$\omega^2 M = -C \left[ \exp(ika) + \exp(-ika) - 2 \right]$$

$$\omega(k)^2 = \left( \frac{2c}{M} \right) (1 - \cos(ka))$$

$$\omega(k)^2 = \frac{4c}{M} \sin^2 \left( \frac{1}{2}ka \right)$$

$$\implies \omega(k) = \sqrt{\frac{4c}{M}} \left| \sin \left( \frac{1}{2}ka \right) \right|$$

- > angular frequency depends on the wavevector phenomena is known as dispersion
- ➤ waves of certain wavelength or wavevector travel at different velocities

#### **5.1** Group Velocity

➤ consider displacement of planes as a packet of elastic energy propagating through a crystal (phonons)

$$v_g = \frac{\partial \omega}{\partial k}$$

 $\triangleright$  velocity is related to the gradient of  $\omega(k)$  dispersion curve

$$v_g = \sqrt{\frac{Ca^2}{M}} \cos\left(\frac{1}{2}ka\right)$$

- ➤ low wavevector waves have higher velocity, waves at boundary of Brillouin zone have zero velocity
- **5.2** Long Wavelength Limit
  - ▶ applies to waves  $k \approx 0$ , defined by  $ka \ll 1$
  - ➤ this corresponds to sound waves in crystal
  - ▶ when  $ka \ll 1 \to \cos(ka) = 1 \frac{1}{2}(ka)^2$
  - ➤ dispersion relation (long wavelength):

$$\omega^2 = \left(\frac{c}{M}\right) k^2 a^2$$
$$\omega = \sqrt{\frac{c}{M}} ka$$

 $\blacktriangleright \omega \propto k$  at long wavelengths

# Lecture 6

- > consider two atom basis in phonon model e.g. salts (NaCl), semiconductors (GaAs), etc
- ▶ use same equation of motion with  $M_1$  and  $M_2$  masses and  $U_{s,s\pm 1}...,V_{s,s\pm 1}...$

$$M_1 \frac{d^2 U_s}{dt^2} = c(V_s + V_{s-1} - 2U_s) \; ; \; M_2 \frac{d^2 V_s}{dt^2} = c(U_{s+1} + U_s - 2V_s)$$

- $\triangleright$  solutions is SHM travelling wave, different amplitudes on adjacent planes  $u_s, v_s$
- $\blacktriangleright$  we define a as the distance between identical planes  $(M_1 \text{ or } M_2)$

$$U_s = U \exp(isKa) \exp(-i\omega t)$$
;  $V_s = V \exp(isKa) \exp(-i\omega t)$ 

➤ substitute travelling wave into equation of motion

$$-\omega^2 M_1 U = cv[1 + \exp(-iKa)] - 2cu$$
$$-\omega^2 M_2 V = cu[1 + \exp(iKa)] - 2cv$$

➤ only solution obtained from determinant of matrix equation

$$\begin{vmatrix} 2c - M_1 \omega^2 & -c[1 + \exp(iKa)] \\ -c[1 + \exp(iKa)] & 2c - M_2 \omega^2 \end{vmatrix} = 0$$

$$M_1 M_2 \omega^4 - 2c(M_1 + M_2)\omega^2 + 2c^2(1 - \cos(Ka)) = 0$$

$$\frac{c(M_1 + M_2)}{M_1 M_2} \pm \frac{C(M_1 + M_2)}{M_1 M_2} \sqrt{1 - 2\frac{M_1 M_2(1 - \cos(Ka))}{(M_1 + M_2)^2}} = \omega^2$$

- ➤ solution gives two branches in phonon dispersion relation
- ➤ consider two limits to illustrate general behaviour
  - 1. when  $Ka \ll 1$  long wavelength limit
  - 2.  $K=\pm \frac{\pi}{a}$  boundary of first Brillouin zone
- rightharpoonup for small Ka (long wavelength limit),  $\cos(Ka) \approx 1 \frac{1}{2}K^2a^2$
- ➤ two solutions of dispersion:

$$\omega^2 \approx 2c \left(\frac{1}{M_1} + \frac{1}{M_2}\right)$$
 
$$\omega^2 \approx \frac{\frac{1}{2}c}{M_1 M_2} K^2 a^2$$

- 1.  $\omega$  is independent of K in the optical branch
  - **▶** two atoms out of phase
- 2.  $\omega \propto K$  in the acoustic branch
  - two atoms move in phase
- **6.1** Thermal Properties of Crystals
  - ➤ phonon heat capacity:

$$C_V = \left(\frac{dU}{dT}\right)_V$$

- $\triangleright$   $C_V$  used because no work done to change volume
- ightharpoonup U is the total internal energy of the vibrating lattice

$$U_{tot} = \sum_{k} \sum_{p} U_{kp} = \sum_{k} \sum_{p} \langle n_{kp} \rangle \hbar \omega_{kp}$$

 $\blacktriangleright$  where k is the wavevector, and p is the polarisation, and  $\langle n_{kp} \rangle$ 

 $\triangleright$   $\langle n_{kp} \rangle$  described by Planck distribution function:

$$n = \frac{1}{\exp\left(\frac{\hbar\omega}{k_B T}\right) - 1}$$

➤ number of vibrational nodes is called the density of states - number of vibrations per unit energy

$$D(\omega) = \frac{dN}{d\omega} = \left(\frac{vK^2}{2\pi^2}\right) \left(\frac{dK}{d\omega}\right)$$

- rumber of phonon nodes in a given frequency or energy range
- **6.2** Debye Model
  - ➤ assumption is that velocity of sound is constant
  - $\triangleright$  Debye model dispersion relation:  $\omega = vK$
  - ➤ density of states goes to

$$D(\omega) = \frac{V\omega^2}{2\pi^2 v^3} \; ; \; D(\omega) \propto \omega^2$$

➤ maximum frequency range is Debye frequency:

$$\omega_D^3 = 6\pi^2 v^3 \frac{N}{V}$$

> corresponds to Debye wavevector:

$$K_D = \frac{\omega_D}{v} = \left(6\pi^2 \frac{N}{V}\right)^{1/3}$$

- 6.3 Einstein Model
  - ➤ assumes all phonons have the same frequency or energy

$$U = N\langle n \rangle \hbar \omega = \frac{N\hbar \omega}{\exp\left(\frac{\hbar \omega}{kT}\right) - 1}$$

 $\triangleright$  N is the total number of oscillators

# Lecture 7

- Electrical Properties of Crystals from Classical Physics
  - ➤ assumptions:
    - 1. outer valence electrons are detached free to move through the crystal
    - 2. electric field due to other electrons and nucleus cancel out
  - ➤ Drude model applied kinetic theory of gases to electrons
  - 1. specific heat capacity of electrons
    - ➤ Mean kinetic energy  $E = \frac{3}{2}k_BT$
    - $\blacktriangleright$  specific heat capacity per electron:  $C_V = \frac{dE}{dt} = \frac{3}{2}k_B$
  - 2. electrical conductivity
    - $\blacktriangleright$  begin with Ohm's Law, V = IR
    - $\triangleright$  rewrite in dimensionless form,  $E = \rho J$

    - ➤ Drude model assumes electrons collide with something
    - $\blacktriangleright$  describe using a mean time between collision events  $\tau$

    - ▶ equations of motion  $\underline{v} = \underline{v}_0 \frac{|e|t\underline{E}}{m_e}$ ▶ electron velocity  $v_0$  is random no overall contribution

- ightharpoonup considers only drift velocity in response to  $\underline{E}$
- $\Rightarrow$  electron drift velocity is average of  $-\frac{|e|tE}{m}$

$$\frac{\bar{v}}{\bar{v}} = -\frac{|e|\bar{t}\underline{E}}{m_e}, \ \bar{t} = \tau$$

$$\underline{J} = -n|e|\underline{v} = \frac{n|e|^2\tau}{m_e}\underline{E}$$

$$\Rightarrow \sigma = \frac{n|e|^2\tau}{m_e}$$

- ➤ this is the Drude electrical conductivity formula
- 3. thermal conductivity of electrons

  - ➤ temp gradient  $\frac{dT}{dz}$ ➤ assume electron is in thermal equilibrium at point of collision
  - ➤ consider thermal energy carried by the electron
  - ► thermal average is  $v_z^2 = \frac{k_B T}{m_e}$

$$Q = -nv_z c_V v_z \tau \frac{dT}{dx}$$
$$= -\kappa \frac{dT}{dz}$$
$$\kappa = \frac{3}{2} n \frac{k_B^2 T}{m_e} \tau$$

> comparison with ratio of thermal to electrical conductivity

$$\frac{\kappa}{\sigma} = \frac{3}{2} \left(\frac{k}{e}\right)^2 T$$

## Lecture 8

#### Free Electron Model 8.1

#### Assumptions:

- 1. outer valence electrons detach free to move around crystal
- 2. effects of ions and electrons cancel electrons move in region of no potential
- $\blacktriangleright$  free electron model treats metal as empty box (zero potential) of dimensions  $(L_x, L_y, L_z)$ 
  - inside the box, zero potential
  - → outside the box, infinite potential

### **Periodic Boundary Conditions**

➤ boundary used in this model - consequence of periodicity of crystals

$$\psi(\underline{r}) = \psi(\underline{r} + \underline{L}), \underline{L} = (L_x, L_y, L_z)$$

- $\blacktriangleright$  wavefunction is assumed to be periodic with dimensions of sample space,  $\underline{L}$
- $\triangleright$  this removes any limitation on the value of r

$$\psi(x, y, z) = \psi(x + L_x, y, z) + \psi(x, y + L_y, z) + \psi(x, y, z + L_z)$$

#### Free Electron Wavefunction

➤ potential inside box is zero, so time-independent Schrodinger is

$$-\frac{\hbar^2}{2m_e}\nabla^2\psi(\underline{r}) + V(\underline{r})\psi(\underline{r}) = E\psi(\underline{r})$$

$$\psi(x, y, z) = A \exp\left[i(k_x x + k_y y + k_z z)\right], k_i = \frac{2\pi(l/m)}{L_i}$$
$$E = \frac{\hbar^2}{2m_e} \left(k_x^2 + k_y^2 + k_z^2\right)$$

- ➤ electron energy eigenstates are stationary (independent of time)
- ➤ amplitude A is constant, uncertainty in position coordinate, all energy states overlap

### k-space

- ➤ reciprocal space
- ➤ can describe electrons using k-coordinate
- $\blacktriangleright$  each electron has coordinate  $(k_x, k_y, k_z)$  in k-space, separated by  $\frac{2\pi}{l}$  in each dimension
- ▶ allowed points form mesh in k-space each within a volume  $\left(\frac{2\pi}{L}\right)^3$ 
  - ⇒ "exclusion zone"
  - → no other allowed k-states within the volume
- ➤ each k-state has 2 electron spin degeneracy Pauli exclusion principle
- ➤ allowing for spin, we have

$$2 \div \left(\frac{2\pi}{L}\right)^3 = \frac{L^3}{4\pi^3}$$

### Fermi Energy and Surface

- ➤ maximum energy of system
- ➤ define Fermi energy as highest occupied energy level when system is in ground state (0 Kelvin)

$$E = \frac{\hbar^2 k^2}{2m_e}$$

- $\triangleright$  surface of constant energy is constant,  $k^2$
- $\blacktriangleright$  Fermi surface is a sphere of radius  $k_F$
- ►  $\frac{L^3}{4\pi^3}$  electron states per unit volume, so volume of sphere is  $V = \frac{4}{3}\pi k_F^3$
- ➤ total number of electrons:

$$N = \left(\frac{4}{3}\pi k_F\right)^3 \left(\frac{L^3}{4\pi^3}\right)$$

$$k_F = \left(\frac{3N\pi^2}{L^3}\right)^{1/3} = (3\pi^2 n)^{1/3}, n = \text{ electron density}$$

$$E_F = \frac{\hbar^2}{2m_e} k_F^2 = \frac{\hbar^2}{2m_e} (3\pi^2 n)^{2/3}$$

## **Density of States**

- ➤ number of electron energy states per unit energy range
- $\triangleright$  consider volume of k-space between k and  $k + \delta k$ :
  - $\rightarrow$  volume is surface area  $\times \delta k = 4\pi k^2 \delta^2$
- $\blacktriangleright$  number of states between k and  $k + \delta k \rightarrow$

$$n(k)\delta k - \frac{L^3}{4\pi^3} 4\pi k^2 \delta k$$

➤ express energy:

$$n(E)\delta E = \frac{L^3}{\pi^2}k^2\delta k \implies n(E) = \sqrt{2}\frac{L^3}{\pi^2}\frac{n_e^{3/2}}{k^3}\sqrt{E}$$

# Lecture 9

#### 9.1 Fermi-Dirac Distribution

- Fermi energy is energy of highest occupied state at 0 Kelvin (overall ground state)
- ➤ Fermi function describes occupation of energy levels
- $\blacktriangleright$  at 0 Kelvin, states above  $E_F$  are empty f=0, states below  $E_F$  are occupied f=1
- ➤ define an occupation number:

$$f(E) = \begin{cases} 1 & 0 < E \le E_F \\ 0 & E > E_F \end{cases}$$

> can be considered a continuous distribution function

$$N = \int_0^{E_F} n(E)dE = \int_0^i nfty f(E)n(E)dE$$

- $\triangleright$  consider how function varies with temperature energy range covering transition from f=1 to f = 0 is broadened out at finite temperatures
- ➤ this is described by the Fermi-Dirac distribution function derived by considering 3 constraints:
  - 1. Conservation of Energy
  - 2. Conservation of Particle Number
  - 3. Subject to Pauli Exclusion principle

$$f(E) = \frac{1}{1 + \exp\left[\frac{(E - E_F)}{k_B T}\right]}$$

- ➤ this is a normalised statistical distribution function
- $\triangleright$  describes the probability of energy state E being occupied by an electron

### Behaviour of Fermi-Dirac Function

- $\triangleright$  at low temperatures,  $k_BT \ll E_F$

- 1. when  $E < E_F \to \frac{E E_F}{k_B T} \to \text{large}$  and negative 2. when  $E > E_F \to \frac{E E_F}{K_B T} \to \text{large}$  and positive,  $f(E) \approx 0$ 3. when  $E \approx E_F$ , transition from  $f(E) = 1 \to f(E) = 0$  occurs over narrow energy range around  $E_F$ - width is about  $k_BT$  on each side of  $E_F$
- $\blacktriangleright$  in systems with low densities of electrons,  $f(E) \ll 1$ 
  - ightharpoonup approximation, when  $E_F \ll k_B T$ :

$$f(E) \approx \exp\left[-\left(\frac{E - E_F}{k_B T}\right)\right] \approx \exp\left(-\frac{E}{k_B T}\right)$$

 $\rightarrow$  this behaves like the classical system, very low  $E_F$ 

### Free Electron Heat Capacity

- > can determine the electronic specific heat capacity using free electron model
- ➤ what happens when temperature is increased?
- $\triangleright$  only small proportions of electrons will increase their energy those that are within  $k_BT$  of  $E_F$
- > we require am empty electron state for the excited electron to move to
- $\blacktriangleright$  electrons within region  $k_BT$  of  $E_F$  will absorb thermal energy
- $\blacktriangleright$  assume number of electrons with energy close to  $E_F$  is given by  $n(E_F)k_BT$
- $\triangleright$  extra energy acquired by electron is  $k_BT$

$$U(T) - U(0) = n(E_F)(k_B T)^2$$
 – only for electrons

 $\blacktriangleright$   $n(E_F)$  is the density of states at Fermi energy

$$C_V = \frac{dU}{dT} \approx 2n(E_F)k_B^2 T$$

 $\blacktriangleright$  note that this assumes  $n(E_F)$  is constant over energy range

$$n = \frac{(E_F 2m_e)^{3/2}}{3\pi^2 \hbar^3}$$

$$N = n(E_F)E_F V$$

$$n(E_F) = \frac{3}{2} \frac{N}{E_F}$$

$$C_V \approx \frac{3}{2} k_B T \left(\frac{2k_B T}{E_F}\right)$$

- > specific heat capacity is modified from classical value by bracketed factor
- ➤ electronic specific heat capacity is proportional to temperature

### Lecture 10

- 10.1 Magnetic Properties of Free Electrons
  - ➤ Free electron model can predict magnetic properties
  - ➤ how does metal respond when placed in magnetic field?

# Magnetic Susceptibility of Metals

- ➤ metals develop an induced magnetic moment in magnetic fields
- ➤ interactions between B-field and electron spin
- > it is known all materials show a weak paramagnetism which is independent of temperature
  - → this is parallel to applied field
- ➤ use free electron model to demonstrate this observed effect
- ➤ electrons have a magnetic moment due to spin:

$$\mu_B = \frac{e\hbar}{2m_e} = 9.27 \times 10^{-24} \, J \, T^{-1}$$

- $\triangleright$  energy of electron will change in field by  $\pm \mu_B$  depending on spin
- $\triangleright$  assume equal numbers of  $\pm$  spin for electrons
  - → parallel
  - **→** anti-parallel
- ➤ when B field applied:
  - → half of electrons increase energy by:

$$+\frac{e\hbar}{2m_e}B$$
 - antiparallel

→ half of electrons reduce energy by:

$$-\frac{e\hbar}{2m_e}B$$
 - parallel

- ➤ total energy of system can be reduced if some electrons reverse spins
- ➤ a proportion of electrons with antiparallel spins can reverse spins to reduce overall energy
- ➤ how many electrons reverse spin?
  - ➤ need to have the same Fermi energy for spin up and spin down electrons
- $\triangleright$  density of states function evaluated at  $E_F$  multiplied by change in energy gives number of electrons
- rightharpoonup number of electrons within  $\mu_B B$  of the original Fermi energy:  $ne = \frac{1}{2}n(E_F)\mu_B B$
- $\blacktriangleright$  difference in population:  $n(E_F)\mu_B B$  number of electrons with spin up increased by this amount

 $\blacktriangleright$  net magnetic moment:  $n(E_F)\mu_B^2B$  - produces net magnetic moment per unit volume

$$M = \frac{\mu_B^2 Bn(E_F)}{V}$$

➤ paramagnetic susceptibility, a measure of how easy it is to magnetise system:

$$\chi = \frac{\partial M}{\partial H}, H = \frac{M}{\mu_0} \chi \qquad = \mu_0 \mu_B^2 \frac{n(E_F)}{V}$$

- ➤ this is called the Pauli Paramagnetism it is independent of temperature
- ➤ at finite temperatures, temperature dependence of Fermi distribution will lead to a small temp dependence

#### 10.2 Hall Effect

- ➤ observed in 1879
- $\triangleright$  consider current density, j, flowing along bar in x direction:
- $\triangleright$  apply perpendicular magnetic field, B
- $\blacktriangleright$  electrons experience Lorentz force  $F = e(v \times B + E)$
- ➤ electrons are pushed to one side of metal bar by this force
- $\blacktriangleright$  electric field will compensate for motion due to Lorentz force  $eE_y = -F \implies E_y = -v \times B$
- $\triangleright$  current density, j = nev

$$E_y = -\frac{1}{ne}j \times B, \frac{1}{ne} = R_H$$

- $\triangleright$   $R_H$  is the Hall coefficient
- ➤ the sign of the Hall coefficient shows the charge on the carriers
  - → some metals, however, have positive Hall coefficient

# Lecture 11

#### 11.1 Nearly Free Electron Model

- ➤ free electron model ignored some interactions:
  - 1. electron-atoms free electron approximation
  - 2. electron-electron independent electron approximation
- ➤ nearly free electron model includes electron-atom interactions
- ➤ failures of free electron model:
  - **▶** temperature dependence of conductivity
  - ⇒ some metals have a positive Hall coefficient
- ➤ interaction between electrons and crystal lattices?
  - **▶** lattice  $\underline{R} = n_1\underline{a}_1 + n_2\underline{a}_2 + n_3\underline{a}_3$ , where  $\underline{a}_1, \underline{a}_2, \underline{a}_3$  are lattice vectors

# 11.2 Bloch Theorem

- ➤ this is a consequence of periodic properties of crystals
  - provides insights into behaviour of electrons in periodic potential Bloch states
  - → describes electrons moving in periodic potential
- $\triangleright$  consider a 10 crystal (line of atoms).  $\psi(x)$  is solution satisfying time-independent Schrodinger equation
  - $\rightarrow$  Schrodinger equation has periodic potential V(x) representing atoms
  - $\Rightarrow$  energy eigenvalues,  $\sigma$
- $\triangleright$  Schrodinger equation evaluated at (x+R) must give same solution as as (x)
  - $\rightarrow$  local electronic environment at x and x + R are identical
  - $\rightarrow$  have second solution  $\phi(x)$  which also satisfies the Schrodinger equation with energy E
  - $\rightarrow$  Assume  $\psi$  and  $\phi$  are unique solutions, can write  $\phi(x) = \psi(x+R)$

- ightharpoonup R is lattice vector = na
- $\Rightarrow \psi(x+R) = c(R)\psi(x)$  where c(R) is a constant equal to 1
- ▶ using series of lattice translations,  $c(R_1 + R_2) = c(R_1)c(R_2)$ 
  - $\rightarrow$  therefore  $c(nR) = [c(R)]^n, n \in \mathbb{N}$
- $\blacktriangleright$  wavefunction must satisfy boundary conditions (periodic over M lattice translation where Ma=l, the length of 10 crystals)
- ➤ Bloch theorem brings together two requirements to satisfy both periodic bonding conditions and lattice translation by  $n_1a_1$  where  $n_1$  is an integer
- From this we have  $\psi(x + Ma) = \psi(x) \implies [c(a)]^M = 1$ 
  - ightharpoonup a functions that satisfies replacement for  $c(a) = \exp[ika]$ , where  $ka = \frac{2\pi l}{M}$   $(l \in \mathbb{Z})$
- ▶ for any lattice translation,  $\underline{R} = m\underline{a}$  ( $m \in \mathbb{Z}, \underline{a}$  is lattice constant)
  - $ightharpoonup c(R) = [c(a)]^M \equiv \exp[iMka] = \exp[ikR], R = \frac{2\pi l}{L} l \in \mathbb{Z}, L \text{ is the total dimension of sample}$
- ➤ these statements set out Bloch's theorem they explain the difference between free electron and nearly free electron models
- $\blacktriangleright$  free electron model  $\psi(x) = C \exp[ikx]$  plane wave with constant energy E, k is the electron
- $\blacktriangleright$  nearly free electron model  $\psi(x+R) = C \exp[ik(x+R)] = C \exp[ikR]\psi(x) = Cu_k(R)\psi(x), \ u_k(R)$ is the Bloch function
- ➤ the Bloch theorem tells us that nearly free electron wavefunctions (weak periodic potential) are composed of two parts:
  - 1. plane wave free electron behaviour,  $C \exp[ikx]$
  - 2. modulated in intensity by Bloch function,  $u_k(R)$ , has periodicity of lattice
  - $\rightarrow$  fundamental nature of  $\psi$  is still free electron behaviour, but with a modification

# Consequences of Bloch Theorem

- ▶ adding multiples of  $\frac{2\pi}{a}$  to Bloch wavevectors does not alter solution  $\psi$  ⇒ only k values in  $\frac{2\pi}{a}$  range are physically distinct ⇒ all other values can be mapped into unique range
- $\blacktriangleright$  convention is to define this as  $-\frac{\pi}{a} \to \frac{\pi}{a}$ 
  - ➡ this corresponds to the first Brillouin zone

# **Energy Band Diagrams**

- $\blacktriangleright$  shows electron behaviour in terms of energy and wavevector free electron model  $E = \frac{\hbar^2 k^2}{2m}$
- $\blacktriangleright$  branches of E(k) curve are moved into first Brillouin zone

#### Lecture 12

- 12.1 Nearly Free Electron Energy Bands
  - > physical origin of energy gaps and energy bands:
    - 1. Bragg reflection electron waves can scatter from planes of atoms. Weak periodic potentiation Schrodinger equation. Gives corresponding values for energy gaps at  $k = \frac{n\pi}{a}$
    - 2. interference at certain wavelengths, get interference between electron waves and atoms

#### **Energy Bands**

- ➤ describe relationship between energy and wavevector
- ➤ electrons of different 'k' propagate at different velocities dispersion
- $\blacktriangleright$  travelling wave group velocity:  $v_g = \frac{d\omega}{dk}$
- ➤ For electron:  $v_g = \frac{1}{\hbar} \frac{dE(k)}{dk}$

▶ velocity of Block electrons (know  $E = \frac{\hbar^2 k^2}{2m_e}$ ). This gives:

$$v_g = \frac{1}{\hbar} \frac{d}{dk} \left( \frac{\hbar^2 k^2}{2m_e} \right) = \frac{\hbar k}{m_e} = \frac{p}{m} = vk$$

- $\blacktriangleright$   $\hbar k$  is the crystal momentum
- rystal momentum is the momentum an electron has as a result of interacting with periodic potential
- ➤ exhibits different physical parameters

# Current Carried by Energy Bands

 $\blacktriangleright$  we know that the current density is  $j = ne\langle v \rangle$ , where  $n \equiv$  electron density,  $\langle v \rangle \equiv$  average velocity

$$\langle v \rangle = \frac{1}{\hbar} \int_{k=-\frac{\pi}{a}}^{k=\frac{\pi}{a}} \frac{dE}{dk} dk \, \frac{a}{2\pi}$$

➤ consider 
$$k = \frac{\pi}{a}$$
 nd  $k = -\frac{\pi}{a}$ , these are physically equivalent states (from Block theorem)

⇒ tells us that  $E\left(\frac{\pi}{a}\right) = 0 = E\left(-\frac{\pi}{a}\right)$ 
 $\langle v \rangle = \frac{a}{2\pi\hbar} \left[ E\left(\frac{\pi}{a}\right) - E\left(-\frac{\pi}{a}\right) \right] = 0$ 

- ➤ above implies average velocity of fulled energy band is zero, as is current density
- ➤ completely filled energy band carries no electrical current (insulators)
- ➤ current carried by partially filled bands (metals or semiconductors)

#### 12.2 Equation of Motion for Bloch Electrons

 $\triangleright$  consider force F applied to electron -  $Fv_q$  = rate of work being done

$$Fv_g = \frac{dE}{dt} = \frac{dE}{dk} \times \frac{dk}{dt}$$
$$v_g = \frac{1}{\hbar} \frac{dE}{dk} \implies F = \hbar \frac{dk}{dt}$$

> can predict how electron will respond in electric field

#### 12.3 Effective Mass

- ➤ electrons in Bloch states move as though the mass of electron is different form free electron masses
- rightharpoonup consider E(k) relationship near band edge at  $k=k_0$  where  $\frac{dE}{dk}=0$  (i.e. zero group velocity)
- ▶ general form given by  $E = E(k_0) + \frac{1}{2}A(k k_0)^2$
- rightharpoonup group velocity:  $v_g(k) = \frac{A(k-k_0)}{\hbar}$  compare with free electrons, where we have  $v_{free} = \frac{p}{m_e} = \frac{\hbar k}{m_e}$
- $\blacktriangleright$  electrons behave as though they have an effective mass of  $m_{eff} = \frac{\hbar^2}{A}$
- ▶ from Taylor's theorem, we can show that  $A = \frac{d^2 E}{dk^2}\Big|_{k=k_0}$

$$m_{eff} = \hbar^2 \left[ \frac{d^2 E}{dk^2} \right]_{k=k_0}^{-1}$$

- $\blacktriangleright$  second derivative is curvature when  $E \propto k^2$  then  $m_{eff}$  is constant
- $\blacktriangleright$  some regions of  $m_{eff}$  are positive, some regions are negative
- ➤ negative mass ⇒ electrons slow down in electric field, force is in opposite direction

#### 12.4 Electrons and Holes

- ➤ an energy band which is nearly filled has some vacant energy states near top of energy band
- $\triangleright$  consider vacant states of holes charge of +e, equivalent to negative effective mass
- ▶ hole wavevector  $k_h = -k_e$ , energy  $E(k_h) = -E(k_e), v_h = v_e$
- 1. if energy band is full there is no current
- 2. if energy band is partially full then electrons with  $m_{eff}$  describe electrical response
- 3. if energy band is almost completely filled, then holes with negative  $m_{eff}$ , positive charge